

2N5550  
2N5551

**SILICON  
NPN TRANSISTORS**



**TO-92 CASE**



[www.centrasemi.com](http://www.centrasemi.com)

**DESCRIPTION:**

The CENTRAL SEMICONDUCTOR 2N5550 and 2N5551 are silicon NPN transistors designed for high voltage amplifier applications.

**MARKING: FULL PART NUMBER**

**MAXIMUM RATINGS:** ( $T_A=25^\circ\text{C}$  unless otherwise noted)

	SYMBOL	2N5550	2N5551	UNITS
Collector-Base Voltage	$V_{CBO}$	160	180	V
Collector-Emitter Voltage	$V_{CEO}$	140	160	V
Emitter-Base Voltage	$V_{EBO}$		6.0	V
Continuous Collector Current	$I_C$		600	mA
Power Dissipation	$P_D$		625	mW
Power Dissipation ( $T_C=25^\circ\text{C}$ )	$P_D$		1.0	W
Operating and Storage Junction Temperature	$T_J, T_{stg}$		-65 to +150	$^\circ\text{C}$
Thermal Resistance	$\theta_{JA}$		200	$^\circ\text{C/W}$
Thermal Resistance	$\theta_{JC}$		125	$^\circ\text{C/W}$

**ELECTRICAL CHARACTERISTICS:** ( $T_A=25^\circ\text{C}$  unless otherwise noted)

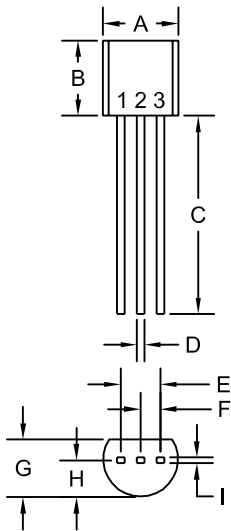
SYMBOL	TEST CONDITIONS	2N5550			2N5551			UNITS
		MIN	TYP	MAX	MIN	TYP	MAX	
$I_{CBO}$	$V_{CB}=100\text{V}$	-	-	100	-	-	-	nA
$I_{CBO}$	$V_{CB}=120\text{V}$	-	-	-	-	-	50	nA
$I_{CBO}$	$V_{CB}=100\text{V}, T_A=100^\circ\text{C}$	-	-	100	-	-	-	$\mu\text{A}$
$I_{CBO}$	$V_{CB}=120\text{V}, T_A=100^\circ\text{C}$	-	-	-	-	-	50	$\mu\text{A}$
$I_{EBO}$	$V_{EB}=4.0\text{V}$	-	-	50	-	-	50	nA
$BV_{CBO}$	$I_C=100\mu\text{A}$	160	-	-	180	-	-	V
$BV_{CEO}$	$I_C=1.0\text{mA}$	140	-	-	160	-	-	V
$BV_{EBO}$	$I_E=10\mu\text{A}$	6.0	-	-	6.0	-	-	V
$V_{CE(SAT)}$	$I_C=10\text{mA}, I_B=1.0\text{mA}$	-	-	0.15	-	-	0.15	V
$V_{CE(SAT)}$	$I_C=50\text{mA}, I_B=5.0\text{mA}$	-	-	0.25	-	-	0.20	V
$V_{BE(SAT)}$	$I_C=10\text{mA}, I_B=1.0\text{mA}$	-	-	1.0	-	-	1.0	V
$V_{BE(SAT)}$	$I_C=50\text{mA}, I_B=5.0\text{mA}$	-	-	1.2	-	-	1.0	V
$h_{FE}$	$V_{CE}=5.0\text{V}, I_C=1.0\text{mA}$	60	-	-	80	-	-	
$h_{FE}$	$V_{CE}=5.0\text{V}, I_C=10\text{mA}$	60	-	250	80	-	250	
$h_{FE}$	$V_{CE}=5.0\text{V}, I_C=50\text{mA}$	20	-	-	30	-	-	
$h_{fe}$	$V_{CE}=10\text{V}, I_C=1.0\text{mA}, f=1.0\text{kHz}$	50	-	200	50	-	200	
$f_T$	$V_{CE}=10\text{V}, I_C=10\text{mA}, f=100\text{MHz}$	100	-	300	100	-	300	MHz
$C_{ob}$	$V_{CB}=10\text{V}, I_E=0, f=1.0\text{MHz}$	-	-	6.0	-	-	6.0	pF
$C_{ib}$	$V_{BE}=0.5\text{V}, I_C=0, f=1.0\text{MHz}$	-	35	-	-	35	-	pF
NF	$V_{CE}=5.0\text{V}, I_C=250\mu\text{A}, R_S=1.0\text{k}\Omega, f=10\text{Hz to } 15.7\text{kHz}$	-	-	10	-	-	8.0	dB

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TO-92 CASE - MECHANICAL OUTLINE



R1

SYMBOL	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A (DIA)	0.175	0.205	4.45	5.21
B	0.170	0.210	4.32	5.33
C	0.500	-	12.70	-
D	0.016	0.022	0.41	0.56
E	0.100		2.54	
F	0.050		1.27	
G	0.125	0.165	3.18	4.19
H	0.080	0.105	2.03	2.67
I	0.015		0.38	

TO-92 (REV: R1)

LEAD CODE:

- 1) Emitter
- 2) Base
- 3) Collector

MARKING:

FULL PART NUMBER

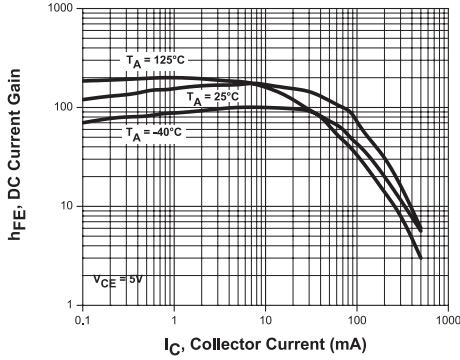
2N5550  
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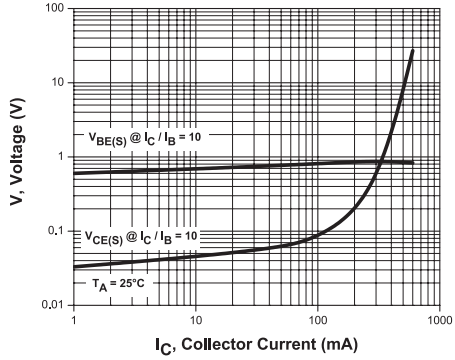


TYPICAL ELECTRICAL CHARACTERISTICS

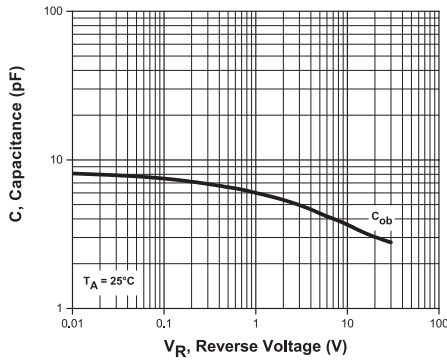
DC Current Gain



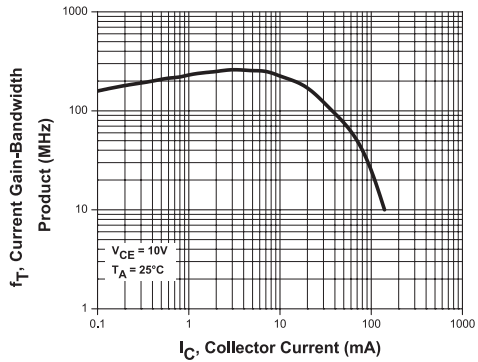
"ON" Voltage



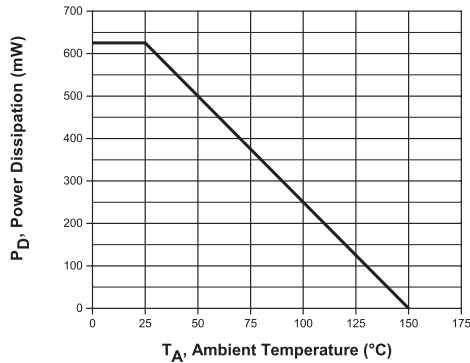
Capacitance



Current Gain-Bandwidth Product



Power Derating



R3 (20-May 2022)

## OUTSTANDING SUPPORT AND SUPERIOR SERVICES



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### PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- Inventory bonding
- Consolidated shipping options
- Custom bar coding for shipments
- Custom product packing

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- SPICE models
- Custom electrical curves
- Environmental regulation compliance
- Customer specific screening
- Up-screening capabilities
- Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- Application and design sample kits
- Custom product and package development

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### REQUESTING PRODUCT PLATING

1. If requesting Tin/Lead plated devices, add the suffix "TIN/LEAD" to the part number when ordering (example: 2N2222A TIN/LEAD).
2. If requesting Lead (Pb) Free plated devices, add the suffix "PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

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### CONTACT US

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